

STTH2002

Ultrafast recovery diode

Features

- Ultrafast switching
- Low reverse current
- Low thermal resistance
- Reduces switching and conduction losses
- High T_i
- Insulating voltage: 2500 V rms
- Capacitance: 7 pF

Description

This single rectifier is suited for switch mode power supply and high frequency DC to DC converters. Packaged in D²PAK, TO-220AC and insulated TO-220AC, this device is intended for low voltage, high frequency inverters, free wheeling and polarity protection applications

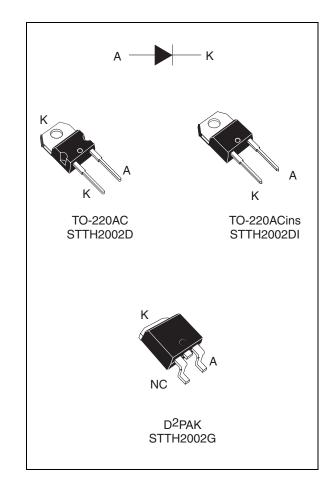


Table 1.Device summary

Symbol	Value
I _{F(AV)}	20 A
V _{RRM}	200 V
T _j (max)	175 °C
V _F (typ)	0.86 V
t _{rr} (typ)	16 ns

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1 Characteristics

Table 2. Absolute ratings (limiting values at T_i = 25 °C, unless otherwise specified)

Symbol	Para	Parameter					
V _{RRM}	Repetitive peak reverse voltage		200	V			
I _{F(RMS)}	Forward rms current	35	А				
	Average ferward everant S 0.5	TO-220AC, D ² PAK	T _c = 120 °C	20	۸		
IF(AV)	Average forward current, $\delta = 0.5$	TO-220ACins	T _c = 60 °C	20	A		
I _{FSM}	Surge non repetitive forward current	175	А				
T _{stg}	Storage temperature range	-65 to + 175	°C				
Т _ј	Maximum operating junction temperatu	re		175	°C		

Table 3.Thermal parameters

Symbol	Para	Parameter			
D kunstien te soos		TO-220AC, D ² PAK		°C/W	
R _{th(j-c)}	Junction to case	TO-220ACins	5	C/ VV	

Table 4.Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _B ⁽¹⁾	Reverse leakage current	$T_j = 25 \ ^{\circ}C$	VV			10	μA
'R'	neverse leakage current	T _j = 125 °C	V _R = V _{RRM}		10	100	μΑ
		T _j = 25 °C	I _F = 20 A		1	1.1	
		T _j = 150 °C	1F - 20 A		0.86	0.95	
V _F ⁽²⁾	Forward voltage drop	T _j = 25 °C				1.15	V
		T _j = 125 °C	I _F = 25 A		0.94	1.05	
		T _j = 150 °C			0.9	1	

1. Pulse test: t_p = 5 ms, δ < 2 %

2. Pulse test: tp = 380 μ s, δ < 2 %

To evaluate the conduction losses use the following equation: P = 0.75 x $I_{F(AV)}$ + 0.01 ${I_F}^2_{(RMS)}$



Table 5.	Dynamic characteristics
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Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
+	Reverse recovery time	$\label{eq:last} \begin{array}{l} I_F = 1 \mbox{ A, } dI_F/dt = -200 \mbox{ A/}\mu s, \\ V_R = 30 \mbox{ V, } T_j = 25 \mbox{ °C} \end{array}$		16	20	ns
t _{rr}		$I_F = 1 \text{ A, } dI_F/dt = -50 \text{ A}/\mu\text{s}, \\ V_R = 30 \text{ V, } T_j = 25 \text{ °C}$		33	40	115
I _{RM}	Reverse recovery current	I_F = 20 A, dI_F/dt = 100 A/µs, V_R = 160 V, T_j = 125 °C		8	10	А
t _{fr}	Forward recovery time	I_F = 20 A, dI_F/dt = 100 A/µs V_{FR} = 1.1 x $V_{Fmax},$ T_j = 25 °C		230		ns
V _{FP}	Forward recovery voltage	$I_F = 20 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s},$ $V_{FR} = 1.1 \text{ x } V_{Fmax}, \text{ T}_j = 25 \text{ °C}$		2		V



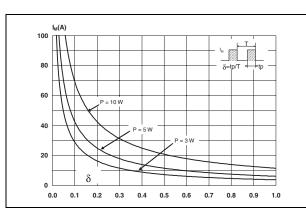


Figure 3. Forward voltage drop versus forward current (maximum values)

Figure 2. Forward voltage drop versus forward current (typical values)

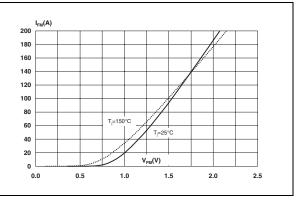
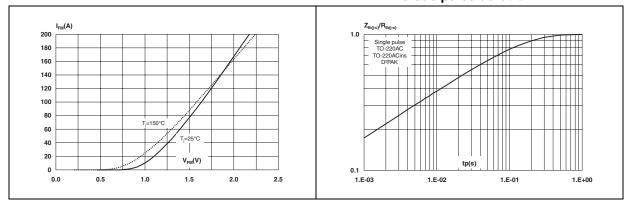
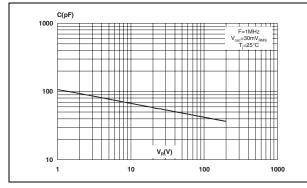


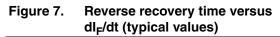
Figure 4. Relative variation of thermal impedance, junction to case, versus pulse duration



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Figure 5. Junction capacitance versus reverse applied voltage (typical values)





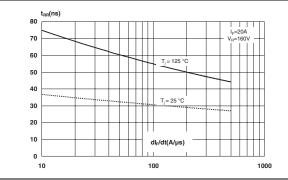
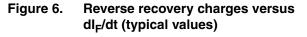


Figure 9. Dynamic parameters versus junction temperature



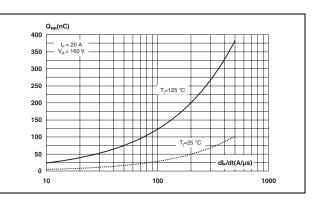


Figure 8. Peak reverse recovery current versus dl_F/dt (typical values)

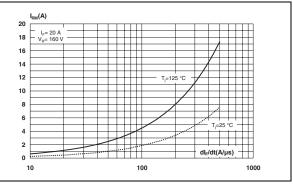
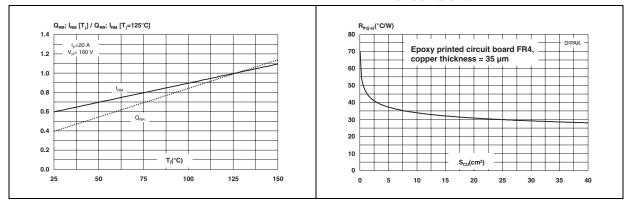
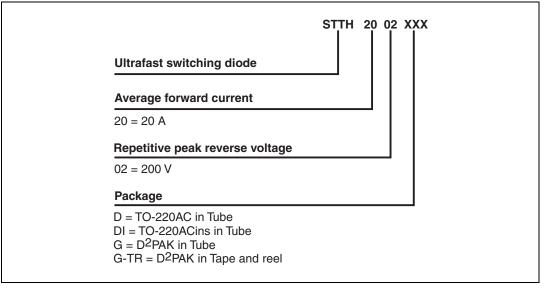


Figure 10. Thermal resistance, junction to ambient, versus copper surface under tab for D²PAK



2 Ordering information scheme

Figure 11. Ordering information scheme





3 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK[®] is an ST trademark.

Table 6. T0-220AC dimensions

			Dimer	nsions	
	Ref.	Millim	Millimeters Inches		
		Min.	Max.	Min.	Max.
	А	4.40	4.60	0.173	0.181
	С	1.23	1.32	0.048	0.051
	D	2.40	2.72	0.094	0.107
	E	0.49	0.70	0.019	0.027
	F	0.61	0.88	0.024	0.034
L2	F1	1.14	1.70	0.044	0.066
$F1 \qquad \downarrow \qquad $	G	4.95	5.15	0.194	0.202
	H2	10.00	10.40	0.393	0.409
F	L2	16.40 typ.		0.645 typ.	
	L4	13.00	14.00	0.511	0.551
	L5	2.65	2.95	0.104	0.116
G	L6	15.25	15.75	0.600	0.620
	L7	6.20	6.60	0.244	0.259
	L9	3.50	3.93	0.137	0.154
	М	2.6	typ.	0.102	2 typ.
	Diam. I	3.75	3.85	0.147	0.151



Table 7. TO-220ACINS dim	chalona				Dime	nsions		
		Ref.	М	illimete			Inches	
			Min.	Тур.	Max.	Min.	Тур.	Max.
		А	15.20		15.90	0.598		0.625
		a1		3.75			0.147	
Ø I	C ba	a2	13.00		14.00	0.511		0.551
	<u>b2</u>	В	10.00		10.40	0.393		0.409
	F	b1	0.61		0.88	0.024		0.034
14 A		b2	1.23		1.32	0.048		0.051
		С	4.40		4.60	0.173		0.181
	€2	c1	0.49		0.70	0.019		0.027
l2 → 4 a2		c2	2.40		2.72	0.094		0.107
	M =	е	4.80		5.40	0.189		0.212
	M ←→ c1	F	6.20		6.60	0.244		0.259
		ØI	3.75		3.85	0.147		0.151
		14	15.80	16.40	16.80	0.622	0.646	0.661
		L	2.65		2.95	0.104		0.116
		12	1.14		1.70	0.044		0.066
		М		2.60			0.102	

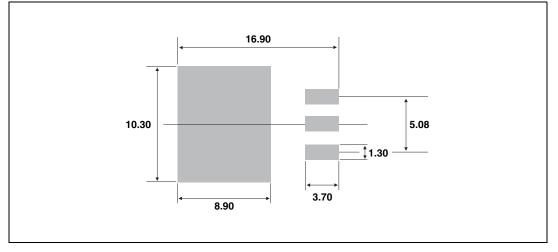
Table 7. T0-220ACins dimensions



				Dimer	nsions	
		REF.	Millim	neters	Inc	hes
			Min.	Max	Min.	Max.
		Α	4.40	4.60	0.173	0.181
	<mark>← A</mark> →	A1	2.49	2.69	0.098	0.106
	C2 →	A2	0.03	0.23	0.001	0.009
		В	0.70	0.93	0.027	0.037
L	D	B2	1.14	1.70	0.045	0.067
		С	0.45	0.60	0.017	0.024
		C2	1.23	1.36	0.048	0.054
		D	8.95	9.35	0.352	0.368
←G		E	10.00	10.40	0.393	0.409
		G	4.88	5.28	0.192	0.208
	2mm min. FLAT ZONE	L	15.00	15.85	0.590	0.624
	V2	L2	1.27	1.40	0.050	0.055
	↓ I#	L3	1.40	1.75	0.055	0.069
		М	2.40	3.20	0.094	0.126
		R	0.40	typ.	0.010	6 typ.
		V2	0°	8°	0°	8°









4 Ordering information

Table 9.Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STTH2002D	STTH2002	TO-220AC	1.90 g	50	Tube
STTH2002DI	STTH2002	TO-220ACins	2.30 g	50	Tube
STTH2002G	STTH2002	D ² PAK	1.48 g	50	Tube
STTH2002G-TR	STTH2002	D ² PAK	1.48 g	1000	Tape and reel

5 Revision history

Table 10. Document revision history

Date	Revision	Changes
03-May-2006	1	First issue.
05-Sep-2011	2	Updated dimension e and deleted I3 in Table 7.



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